

FORM PTO-1449				Atty. Docket No.	Appln. No.		
LIST OF DOCUMENTS CITED BY APPLICANT				XA-9945			
				Applicant Tomoyuki ISHII et al.			
				Filing Date HEREWITH	Group		
U. S. PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
FOREIGN PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
<i>Alh</i>	AJ	2001-156275	6/08/01	Japan	—	—	Abstract
	AK						
	AL						
	AM						
	AN						
	AO						
OTHER (including author, title, date, pertinent pages, etc.)							
<i>Alh</i>	AP	Arai, et al., "High-Density (4.4F ²) NAND Flash Technology Using Super-Shallow Channel Profile (SSCP) Engineering," IEEE International Electron Devices Meeting 2000, pp. 775-778.					
<i>Alh</i>	AQ	Kobayashi, et al., "A Giga-Scale Assist-Gate (AG)-(AND)-Type Flash Memory Cell with 20-MB/s Programming Throughput for Content-Downloading Applications," IEEE International Electron Devices Meeting 2001 pp. 29-32.					
<i>Alh</i>	AR	Eitan, et al., "Can NROM, a 2 Bit, Trapping Storage NVM Cell, Give a Real Challenge to Floating Gate Cells?" International Conference on Solid State Devices and Materials 1999, pp. 522-524.					
Examiner <i>Adrienne</i>				Date Considered			08/08/05
XAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

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